

## STPS3L40-Y

## Automotive power Schottky rectifier

#### **Features**

- Negligible switching losses
- Low thermal resistance
- Low forward voltage drop
- Avalanche capability specified
- ECOPACK<sup>®</sup>2 compliant component
- AEC-Q101 qualified

#### **Description**

Schottky rectifier suited for switched mode power supplies and high frequency DC to DC converters. Packaged in SMC, this device is intended for use in DC/DC chargers for automotive application.

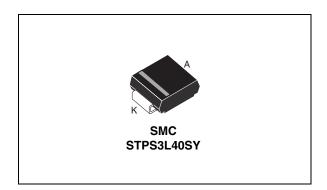


Table 1. Device summary

| Symbol               | Value  |
|----------------------|--------|
| I <sub>F(AV)</sub>   | 3 A    |
| V <sub>RRM</sub>     | 40 V   |
| T <sub>j</sub> (max) | 150 °C |
| V <sub>F</sub> (max) | 0.44 V |

STPS3L40-Y **Characteristics** 

#### **Characteristics** 1

Table 2. **Absolute ratings (limiting values)** 

| Symbol             | Parameter                                                             | Value        | Unit |   |
|--------------------|-----------------------------------------------------------------------|--------------|------|---|
| $V_{RRM}$          | Repetitive peak reverse voltage                                       | 40           | V    |   |
| I <sub>F(AV)</sub> | Average forward current                                               | 3            | Α    |   |
| I <sub>FSM</sub>   | Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$ |              | 75   | Α |
| P <sub>ARM</sub>   | Repetitive peak avalanche power                                       | 1300         | W    |   |
| T <sub>stg</sub>   | Storage temperature range                                             | -65 to + 175 | °C   |   |
| T <sub>j</sub>     | Operating junction temperature range <sup>(1)</sup>                   | -40 to +150  | °C   |   |

 $<sup>\</sup>frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

| Symbol               | Parameter        | Value | Unit |  |
|----------------------|------------------|-------|------|--|
| R <sub>th(j-l)</sub> | Junction to lead | 18    | °C/W |  |

Table 4. Static electrical characteristics

| Symbol                        | Parameter               | Test conditions         |                      | Тур. | Max. | Unit |
|-------------------------------|-------------------------|-------------------------|----------------------|------|------|------|
| I <sub>R</sub> <sup>(1)</sup> | Reverse leakage current | T <sub>j</sub> = 25 °C  | $V_R = V_{RRM}$      |      | 100  | μΑ   |
|                               |                         | T <sub>j</sub> = 125 °C |                      | 16   | 40   | mA   |
| V <sub>F</sub> <sup>(1)</sup> | Forward voltage drop    | T <sub>j</sub> = 25 °C  | I <sub>F</sub> = 3 A |      | 0.5  | V    |
|                               |                         | T <sub>j</sub> = 125 °C |                      | 0.40 | 0.44 |      |
|                               |                         | T <sub>j</sub> = 25 °C  | I <sub>F</sub> = 6 A |      | 0.62 |      |
|                               |                         | T <sub>j</sub> = 125 °C |                      | 0.52 | 0.58 |      |

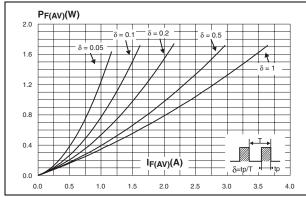
<sup>1.</sup> Pulse test: tp = 380  $\mu$ s,  $\delta$  < 2%

To evaluate the conduction losses use the following equation: P = 0.30 x  $I_{F(AV)}$  + 0.047  $I_{F}^{2}_{(RMS)}$ 

$$P = 0.30 \times I_{E(AV)} + 0.047 I_{E}^{2} (BMS)$$

STPS3L40-Y Characteristics

Figure 1. Average forward power dissipation Figure 2. Average forward current versus versus average forward current ambient temperature ( $\delta$  = 0.5) - SMC



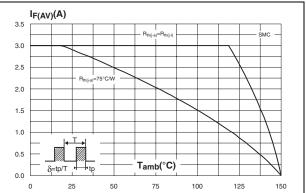
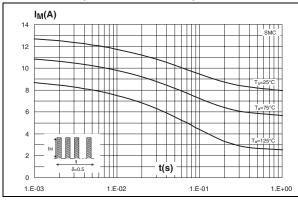


Figure 3. Non repetitive surge peak forward current versus overload duration (maximum values)

Figure 4. Normalized avalanche power derating versus pulse duration



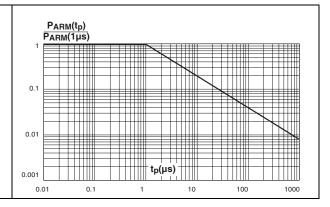
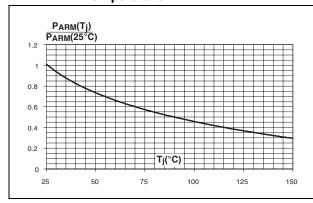
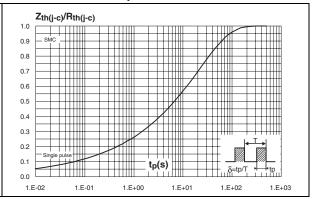


Figure 5. Normalized avalanche power derating versus junction temperature

Figure 6. Relative variation of thermal impedance junction to ambient versus pulse duration

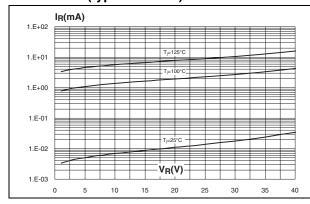




Characteristics STPS3L40-Y

Figure 7. Reverse leakage current versus reverse voltage applied (typical values)

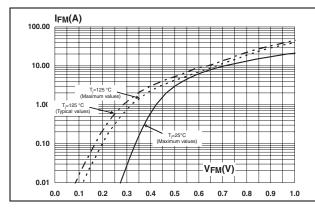
Figure 8. Junction capacitance versus reverse voltage applied (typical values)

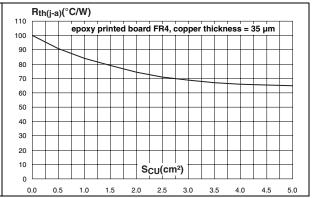


1000 F<sub>100</sub> F<sub>11MHz</sub> F<sub>11MHz</sub>

Figure 9. Forward voltage drop versus forward current

Figure 10. Thermal resistance junction to ambient versus copper surface under each lead





### 2 Package information

- Epoxy meets UL94,V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK® is an ST trademark.

Table 5. SMC package dimensions

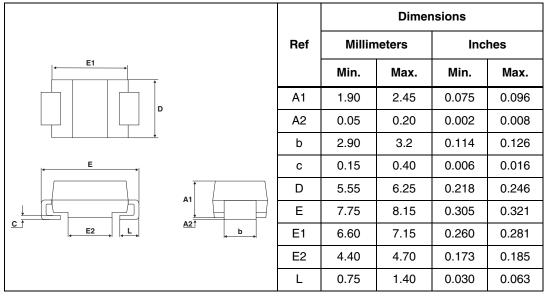
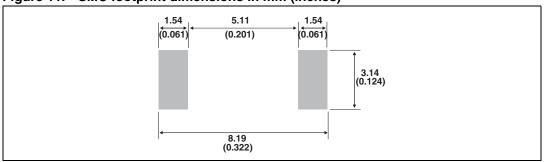


Figure 11. SMC footprint dimensions in mm (inches)



Ordering information STPS3L40-Y

# **3 Ordering information**

Table 6. Ordering information

| Order code | Marking          | Package | Weight | Base qty | Delivery mode |
|------------|------------------|---------|--------|----------|---------------|
| STPS3L40SY | STPS3L40SY S3L4Y |         | 0.24 g | 2500     | Tape and reel |

## 4 Revision history

6/7

Table 7. Document revision history

| Date        | Revision | Changes      |
|-------------|----------|--------------|
| 10-Mar-2011 | 1        | First issue. |

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